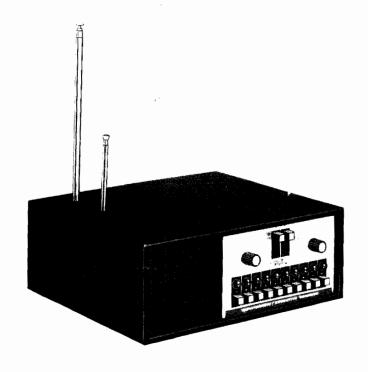
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Regency ELECTRONICS INC.

### SERVICE MANUAL



## MODEL ACT-E10H/L/U MONITORADIO RECEIVER

### ACT-E10 H/L/U SERVICE MANUAL

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### SECTION 1 SPECIFICATIONS AND CIRCUIT DESCRIPTION

### 1-1 SPECIFICATIONS (Subject To Change Without Notice)

### RECEIVER - MODEL ACT-E 10 H/L/U

Frequency Range
VHF Band (Low)
VHF Band (High)
UHF Band (Factory Tuned)
UHF Band (Retuned)
Frequency Separation
VHF Band (Low) 6 DB Bandwidth; 33-47 MHz
10 DB Bandwidth; 30-50 MHz
VHF Band (High) 8 MHz (maximum sensitivity)
12 MHz (usable sensitivity)
UHF Band 8 MHz (maximum sensitivity)
12 MHz (usable sensitivity)
Sensitivity (At Tune-Up)
VHF Band (Low)
VHF Band (High) 0.6 microvolt for 20 DB quieting
UHF Band
Squelch Sensitivity (Threshold)
VHF Band (Low) 0.3 Microvolt
VHF Band (High) 0.5 Microvolt
UHF Band 0.5 Microvolt
Selectivity 6 DB @ ±7 KHz
50 DB @ ±18 KHz
Spurious Rejection (Except Primary Image)
Modulation Acceptance
AFC Range (UHF Only)
I.F. Frequencies
2nd I.F.: 455 KHz (ceramic filter)
Squelch System "Noise Operated"
Audio Output (8 $\Omega$ Speaker)
Distortion; 2 Watts, maximum
FCC Certified Part 15, Subpart C
SCANNER
Scan Rate Approx. 15 Channels per sec.
Scan Delay Approx. 1/2 sec.
DOWER
POWER
Voltage Requirement 105-130 VAC, 60 Hz @ 13 Watts maximum
11-15 VDC @ 9 Watts maximum

Receiver (Squelched)
SEMICONDUCTORS
Integrated Circuits5Silicon Transistors (Total)25Field Effect Transistor1Diodes (Total)30Signal Diodes24Zener Diodes2Rectifier Diodes3Varactor Diode1
GENERAL
Front Panel Size
ACCESSORIES
DC Power Cord

### 1-21 CRYSTAL SPECIFICATIONS

Miniature plug-in crystals are utilized in the receiver. Because of the high accuracy (close tolerance) required, Shepherd Industries' crystals are recommended. If the crystals are ordered from Regency, it is only necessary to specify Part No. 2302-0000-000 for High Band crystals and the desired receive frequency, or Part No. 2303-0000-000 for Low Band crystals and the desired receive frequency, or Part No. 2304-0000-000 for UHF (450-470 MHz) crystals and the desired receive frequency, or Part No. 2320-0000-000 for UHF (470-500 MHz) crystals and the desired receive frequency.

If desired, the crystals may be purchased from other manufacturers. The following specifications must be included in the order:

High Band Crystal: (148-174 MHz)

a. Crystal frequency, determined as follows:

Crystal frequency = Channel frequency -10.7 MHz

3

### EXAMPLE:

Crystal frequency = 155.55 MHz -10.7 MHz = 144.85 MHz = 48.28333 MHz

- b. Frequency Tolerance of .001%
- c. 3rd Overtone
- d. Series resonance minus 450 Hz
- e. Maximum equivalent series resistance of 35 Ohms
- f. Drive Level of 2 MW
- g. Holder: HC-25/U

Low Band Crystal: (30-50 MHz)

a. Crystal frequency, determined as follows: Crystal frequency = Channel frequency +10.7 MHz

### **EXAMPLE:**

Crystal frequency = 39.50 MHz +10.7 MHz = 50.20 MHz

- b. Frequency Tolerance of .001%
- c. 3rd Overtone
- d. Series resonance minus 450 Hz
- e. Maximum equivalent series resistance of 35 Ohms
- f. Drive Level of 2 MW
- g. Holder: HC-25/U

UHF Band Crystal (450-470 MHz)

a. Crystal frequency = Receive frequency -10.7 MHz

### **EXAMPLE:**

Crystal frequency = 458.00 MHz -10.700 MHz

Crystal frequency = 49.70000 MHz

- b. Frequency Tolerance of .001%
- c. 3rd Overtone
- d. Parallel resonance 18 PF load capacitance
- e. Maximum equivalent series resistance of 35 Ohms
- f. Drive Level of 2 MW
- g. Holder: HC-25/U

### UHF Band Crystal (470-500 MHz)

a. Crystal frequency =  $\frac{\text{Receive frequency -}10.7 \text{ MHz}}{10}$ 

### EXAMPLE:

Crystal frequency = 485.10 MHz -10.7 MHz

Crystal frequency = 47.44000 MHz

- b. Frequency Tolerance of .001%
- c. 3rd Overtone
- d. Parallel resonance 18 PF load capacitance
- e. Maximum equivalent series resistance of 35 Ohms
- f. Drive Level of 2 MW
- g. Holder: HC-25/U

### 1-3 CRYSTAL INSTALLATION AND BAND PROGRAMMING

### Crystal Installation:

Due to the numerous frequencies involved, the crystal is not normally installed by the factory, but by the seller or owner of the unit. Miniature, plug-in crystals are installed by inserting them in receptacles mounted on the printed circuit board.

Prior to installing a crystal, the receiver's Crystal Access Door will have to be removed. Turn the unit over and then rotate the two Access Door fasteners so that the door may be lifted out. It is recommended that the power cord (AC or DC) be disconnected before removing the Access Door. Also, remove the two telescopic antennas.

Carefully install the crystal in the proper pair of socket pins as indicated in the Crystal Location Drawing 3-7. The crystal MUST be installed in the proper row for correct operation. The numbers located between two of the rows of pins indicate which group of pins correspond to the channel number on the front panel.

NOTE: Later production units have a Crystal Installation Diagram label affixed to the inside surface of the Access Door.

If the crystal is for the UHF band (450 to 500 MHz), it should be installed with one lead in a center row pin (labeled COMMON) and its other lead in the corresponding pin in the row labeled UHF (row on the right, as viewed from the front of the unit). If the crystal is for one of the VHF bands (either High or Low), it should be installed with one lead in a center row pin and its other lead in the corresponding pin in the row labeled VHF (on the left as viewed from the front of the unit). Thus, one of the crystal's leads must always be inserted in a cen-

ter row socket pin while its other lead is inserted in the proper corresponding outer row socket pin.

### Band Programming:

As shipped from the factory, the first three channels are programmed for Low Band VHF, the next four (Channels 4 through 7) are programmed for High Band VHF and the last three (Channels 8 through 10) are programmed for the UHF Band. If desired, this arrangement can be changed to any other combination of High, Low or UHF Band channels. Remove the Crystal Access Door, as described above, and follow the detailed instructions in the next three paragraphs.

If a channel is to be re-programmed (change bands), remove the proper color-coded wire and socket from its present pin and place it onto the corresponding pin in the desired band row. Each row is labeled (see Crystal Location Diagram 3-7) for its respective band (Hi, Lo or UHF). The outer row of pins on the left side (as viewed from the front) is for the Low VHF Band; the center row is for the Hi VHF Band and the other outer row (on the right side, as viewed from the front) is for the UHF Band.

Be sure that each channel has its color-coded wire programmed properly with respect to the crystal installed and to the channel number. Reading from rear to front (Channel 1 through 10), the color-coded wires should be in this order; brown, red, orange, yellow, green, blue, purple (or violet), pink, white and black.

NOTE: If a particular channel is not used (in other words, there is no crystal installed for that channel), the band selection wire must still be connected to either a High Band, a Low Band or to a UHF Band pin. Thus, for proper scanner operation, all of the band selection wires MUST be connected, even though not all channels are used.

After the crystals are installed and any necessary band programming changes are completed, reinstall the Crystal Access Door. Place the door in its opening and rotate the two fasteners so that they are firmly holding the door in place. Turn the unit over; plug the power cord back in and reinstall the two telescopic antennas.

### 1-4 MAIN BOARD — CIRCUIT DESCRIPTION

Q101 is a Low VHF Band RF amplifier with broad-band tuned circuits in its input and output circuitry. The output of the RF amplifier is coupled to the input of the Low VHF Band mixer, Q102.

Q103 is a High VHF Band RF amplifier with broad-band circuits in its input and output circuitry. The output of the RF amplifier is coupled to the input of the High VHF Band mixer, Q104.

Q105 is the UHF Band Field Effect RF transistor used in the common gate configuration. Q105 has broad-band tuned circuits in its input and output circuitry. The output from the RF amplifier is coupled to the input of the UHF Band mixer, Q106.

The first L.O. (local oscillator), Q125, uses third overtone crystals and operates on all VHF channels, whether High or Low Band. For Low VHF Band signals, the fundamental frequency of the crystal is taken off the Emitter of Q125 for injection. For High VHF Band signals, the third harmonic of the crystal is coupled off the collector of Q125 for oscillator injection. For UHF Band signals, the third harmonic of the crystal is coupled off the collector circuitry of Q107 (the first L.O. for UHF) and is coupled to the base of Q108. Q108 is a tripler which multiplies the 3rd harmonic of the UHF oscillator (Q107) by three for use as the ultimate injection frequency.

The radio is switched between Low VHF Band, High VHF Band and UHF Band by transistors Q113, Q114 and Q115. When Q113 is conducting, operating bias is applied to the Low VHF Band RF amplifier and mixer. When Q114 conducts, operating bias is applied to the High VHF Band RF amplifier and mixer. When Q115 conducts, operating bias is applied to the UHF Band mixer. Conduction of Q113, Q114 or Q115 is determined by the Band Programming pins. A wire socket for each particular channel is connected to either a Low, High or UHF programming pin. When that particular channel is scanned, the Low, High or UHF section is also turned on, depending upon the band programming.

There are three row of crystal socket pins. The middle or center row is common to the diode switching circuitry (CR 101-110, R 125-134, L109-118), thus one pin or lead of the crystal is always inserted in the center row. The other crystal lead is inserted in the associated socket in one of the two outer rows, depending upon whether it is a VHF or UHF crystal.

A crystal is electrically connected to one of the oscillator circuits when its associated diode is forward biased. Until the scanner reaches that particular channel, the diode is back biased and prevents the oscillator from operating on the crystal's frequency. When the respective channel is reached, the scanner's output line provides a low resistance path to ground, which turns the diode on (forward biases it) and effectively connects the crystal into the oscillator circuit.

The automatic frequency control circuit (AFC), UHF Band only, consists of Q109, Q110, Q111 and CR111. Q110 and Q111 form a differential amplifier. The voltage at pin 1 of IC102 is determined by the amount the signal is off frequency; this is called an error voltage. The error voltage is first fed to the differential amplifier pair (Q110 and Q111) and then amplified by Q109 and applied to CR111. CR111 is a voltage variable capacitor, or varactor, in the UHF oscillator (Q107) circuit. When the voltage applied to CR111 changes, the frequency of the oscillator is changed.

The second L.O. frequency is normally 10.245 MHz. In cases where interference is encountered from a signal approximately 910 KHz BELOW the desired frequency, the second L.O. may be changed to 11.155 MHz. If the second L.O. is 10.245 MHz, the error voltage is taken from the collector of Q111. If the second L.O. has been changed to 11.155 MHz, the error voltage is taken from the collector of Q110. The correct combination can be determined by checking the frequency stamped on the second L.O. crystal, (Y111).

The output frequency from the first mixers is 10.7 MHz, the first IF frequency. It is filtered by L122, L123 and L124 before it is fed to an Integrated Circuit IC101, which contains the second mixer circuitry and L.O. circuitry.

The 455 KHz output of IC101 (terminal 5) is coupled through a tuned circuit to the input of the ceramic filter, CF101. CF101 is a narrow-band filter centered at 455 KHz. The excellent bandpass characteristics of CF101 provide for very good adjacent channel rejection. The output of CF101 is amplified by Q116 and coupled through another tuned circuit to the input of Integrated Circuit IC102. IC102 is a series of amplifiers providing approximately 60 DB gain at 455 KHz. Also included in IC102 is the limiting circuitry and a Quadrature Detector circuit. L128, connected between terminals 2 and 12 of IC102, is the adjustable Quadrature coil.

The audio output from IC102 (terminal 1) is coupled to the input of the audio amplifier circuit and to the input of the noise-operated squelch circuit.

Transistor Q117 is an amplifier whose frequency response extends from approximately 5 KHz to 25 KHz. Q117 amplifies the "noise" occuring in this frequency range. The noise is coupled to the base of Q118. Q118 is used as a detector which rectifies the amplified noise and produces a DC voltage at its collector. When the DC voltage at the collector of Q118 is positive and of sufficient value to provide base bias for Q119, Q119 turns off and removes forward bias from diode, CR113 and leaves it back biased. This action prevents audio from reaching the speaker and the receiver is squelched (muted). When a signal (carrier) arrives, the output from the detector Q118 is reduced to the point where the DC voltage at the base of Q119 is no longer sufficient to cause Q119 to conduct.

At this time, CR113 is forward biased and is allowed to conduct normally and the audio output of the unit is heard. Audio is applied through the volume control to IC103. IC103 is an Integrated Circuit containing a power audio amplifier; gain is internally fixed at 34 DB or 50 times and the output is short-circuit proof with internal thermal limiting. The output of IC103 is connected to an 8 ohm internally mounted speaker. An external speaker can be connected to the unit; no less than a 8 ohm speaker is recommended for optimum performance.

The squelch tail circuit consists of R184, R185, CR112, and C170. This circuit is used to keep the squelch circuit open for a short time after the station signal goes off. The purpose of the squelch tail circuit is to prevent the squelch circuits

from chopping very weak signals, especially mobile signals. The timing of the squelch tail can be changed by changing the value of C170. Removing C170 from the circuit will remove the squelch tail completely.

Five basic functional circuits make up the Scanner system. They are; a 4-bit binary counter, a binary coded decimal to one of ten decoder/driver, a lamp detector, a three-speed clock and a clock inhibitor.

The 4-bit binary counter (IC104) has four output (pins 8, 9, 11 and 12) and two inputs. One of the inputs (pin 1) accepts clock pulses and the other one (pin 14) accepts pulses from pin 11 of the counter. The counter counts the clock pulses (up to 16) and provides a binary-coded decimal (BCD) output for each input pulse. This is basically accomplished by having four divide-by-two sections (Flip-Flops) interconnected in a series circuit.

There is a specific combination, in a binary form, of these counter outputs for each channel. The Decoder/Driver (IC105) converts the BCD information into decimal configuration (0 through 9) and provides the "Low" output necessary to turn on the channel lamp and diode switch for the crystal. Only one Decoder/Driver output is low at any one time; all other outputs are "High" or near the supply voltage.

The duration for the lamp to be on is dependent upon the position of the channel switch and the Scan/Manual Switch. If the channel switch is set to the "OUT" position, the lamp does not light at all and the Lamp Detector (Q120) remains cut off (no collector current). The clock runs at its FAST speed (approximately 1200 Hz) and the receiver's oscillator and squelch circuits can not react quickly enough to stop on the channel even if a RF signal were present.

If the channel switch is in the "IN" position, the channel lamp lights and the Lamp Detector (Q120) conducts, forcing the clock to run at its NORMAL (approximately 15 Hz) scan speed. Thus, the lamp is on long enough to reach normal illumination and the receiver's oscillator and squelch circuits can react quickly enough during this relatively long period of time to an incoming RF signal. It should be noted that the Clock runs at its FAST speed except when scanning through an active channel. In other words, until the Lamp Detector (Q120) determines that a channel lamp is drawing current, the Clock is operating in its FAST mode and it does not slow down to its NORMAL scan speed until it actually is partly into an active (lamp lit) channel.

When an RF signal is present, squelch is "broken" and a positive voltage is fed to the Clock Inhibitor (Q121) which then stops the clock from running. Thus, as long as an RF signal (carrier) is present, the clock is stopped and the Counter is not operative. After the RF signal is gone, a delay to the Clock starting again is provided by capacitor C179. This delay permits a short interval of a "stopped" clock so that another RF signal responding to the first signal (for example a mobile replying to the base station) can come on channel without the scanner going through all of the other channels first.

The Clock (pulse generator) circuitry is primarily a unijunction oscillator. Its basic speed (frequency or period) is determined by R 197 and C181, which is the FAST speed. Its NORMAL speed is determined by R 197, C180 and C181. When Q122 is turned on (Q121 turned off, Q120 turned on), C180 is effectively added to the timing circuit of the clock, forcing it to run much slower (approximately 15 Hz).

The Clock Inhibitor, Q121, stops the Clock when it is conducting and its collector goes low (near ground). This provides a low voltage path to ground for the Emitter of the unijunction (Q123). When the Emitter of Q123 is below a certain value, the unijunction ceases to oscillate. It can be considered a solid-state version of the relaxation type oscillator.

For normal scanning operating, the Scan/Manual switch connects the carrier delay capacitor (C179) to the Clock Inhibitor's collector circuit. For manual operation, C179 is connected in parallel with C180. Also, fixed voltage is applied to the base of Q121 which is turned on (conducting), thus stopping the Clock. Then, when the Step switch is pushed in, it removes this fixed voltage from Q121's base, permitting the Clock to run. However, with C180 and C179 in parallel, the Clock will now run at approximately 2 Hz, which is the SLOW or manual stepping scan rate. Upon release of the Step Switch, the Clock Inhibitor (Q121) is again forced to stop the Clock. Pushing in the Scan/Manual switch will automatically let the Clock run again at its proper scan rate.

### 1-5 470-500 MEGAHERTZ OPERATION

This unit can be retuned to cover an eight Megahertz segment of the 470-500 MHz band. The major difference is that the crystal frequency is determined by taking the channel frequency minus 10.7 MHz and dividing by TEN (Refer to Section 1-2, CRYSTAL SPECIFICATIONS). This allows for L119, the drive coil for the UHF tripler, (Q108), not to be retuned. However, C139, the UHF Band injection tuning capacitor, is retuned to 10th harmonic of the crystal. Tuning procedure for 470 to 500 MHz operation is the same as in the UHF Section alignment, see Section 2-4 for proper RF Alignment.

### **SECTION 2 ALIGNMENT AND TUNING PROCEDURE**

### 2-1 EQUIPMENT REQUIRED

- 2-1-1 FM Signal Generator
- 2-1-2 Oscilloscope
- 2-1-3 AC VTVM

NOTE: During all steps of alignment, the squelch control should be in the maximum clockwise position (minimum squelch action).

All receiver RF sections, (Low, High and UHF) should be aligned to the channel nearest the center of the frequency range in the band over which they will operate.

### 2-2 QUADRATURE DETECTOR

- 2-2-1 Connect the FM Signal Generator to the H/L antenna input jack. Accurately set the frequency to the center of the channel being used for alignment. Modulate Signal Generator Generator with 1000 Hz, 3 KHz deviation.
- 2-2-2 Connect the oscilloscope to Junction of C162, C163 and R172.
- 2-2-3 Adjust Signal Generator's output until all of the noise in the scope pattern just disappears.
- 2-2-4 Adjust L128 for maximum peak to peak amplitude, while maintaining symmetry of the detected signal. When L128 is properly aligned, signal at above Junction should be approximately 0.2 volts RMS with test signal input as noted in 2-2-1.

### 2-3 IF ALIGNMENT

- 2-3-1 Pre-Set the cores of L122, L123 and L124 9 turns in from the outer end of the coil form. This step is usually necessary only if the IF appears to be badly misaligned.
- 2-3-2 Connect AC voltmeter to the Junction of R 167 and the collector of Q116.
- 2-3-3 Set AC voltmeter to the 300 millivolts (or 1 volt) scale.
- 2-3-4 With generator accurately set to the frequency of the center of the channel being used for alignment, increase Signal Generator's output until AC voltmeter reading is mid-range.

2-3-5 Adjust L122, L123 and L124 (in that order) for maximum AC voltmeter reading. Readjust Signal Generator's output to maintain voltmeter reading approximately in the mid-range. Repeat adjustment until no further improvement can be made.

### 2-4 RF ALIGNMENT

### LOW BAND SECTION

2-4-1 Pre-Set the cores of L102 and L103 one turn from the outer ends of the coil form. (NOTE: Due to the broadness of the Low Band Section, presetting the above cores will give you optimum performance over the entire band).

### HIGH BAND SECTION

- 2-4-2 Connect AC voltmeter to the Junction of R 167 and the collector of Q116.
- 2-4-3 Set AC voltmeter to the 300 millivolts scale.
- 2-4-4 Activate High Band channel nearest to center of High Band frequencies being used.
- 2-4-5 With Signal Generator accurately set to the frequency of the center of the channel being used for alignment and connected to H/L antenna input jack, increase Signal Generator's output until AC voltmeter reading is mid-range.
- 2-4-6 Adjust L129, L104, L105 and L106 (in that order) for maximum AC voltmeter reading. Readjust Signal Generator's output to maintain voltmeter reading approximately in the mid-range. Repeat adjustment until no further improvements can be made.

### UHF BAND SECTION

- 2-4-7 Connect AC voltmeter across the speaker terminals; connect Signal Generator to the UHF antenna input jack.
- 2-4-8 With Signal Generator output reduced to zero, adjust the volume control until AC voltmeter reads 1.0 volt of noise.
- 2-4-9 Activate UHF channel nearest to center of UHF frequencies being used.
- 2-4-10 Set Signal Generator accurately to the channel being used and adjust output of Signal Generator until AC voltmeter reads approximately 0.2 volts.

- 2-4-11 Pre-Set trimmer capacitor C139 for minimum capacitance. The movable half-moon section (gold color) should be turned toward the front of the unit.
- 2-4-12 Adjust trimmer capacitors C121 and C122 (in that order) for maximum quieting (lowest meter reading). Adjust Signal Generator's output to maintain a voltmeter reading between 0.1 and 0.2 volts. Repeat adjustments until no further improvement can be made.
- NOTE: Use a non-metallic tool for all trimmer capacitor adjustments. Peaks are very sharp, so tune with care.
- 2-4-13 Adjust the core of L119 for maximum quieting (lowest meter reading).
  Adjust Signal Generator's output to maintain a reading between 0.1 and 0.2 volts.
- 2-4-14 Adjust trimmer capacitor C139 for maximum quieting (lowest meter reading). Adjust Signal Generator's output to maintain a reading between 0.1 and 0.2 volts.
- 2-4-15 Readjust trimmer capacitors C121, C122 and C139 (in that order) for maximum quieting (lowest meter reading). Adjust Signal Generator's output to maintain a voltmeter reading between 0.1 and 0.2 volts. Repeat these adjustments until no further improvement can be made.

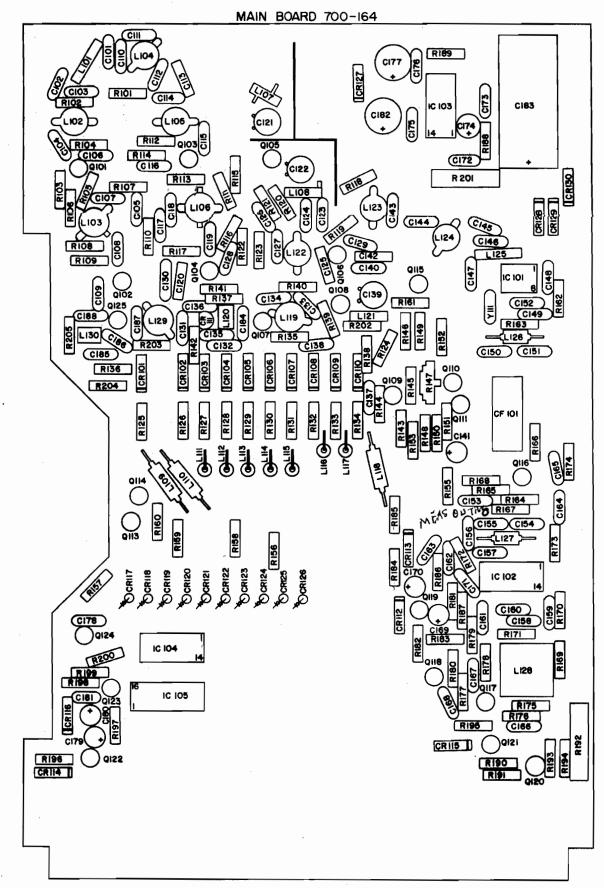
### 2-5 AFC ALIGNMENT

- NOTE: This adjustment requires an accurate 10.7 MHz ±1 KHz oscillator or 455 KHz ±500 Hz oscillator to be used as a reference signal. If none are available, proceed to Step 2-5-4.
- 2-5-1 With a coupling loop, inject "Reference" signal (either 10.7 MHz or 455 KHz) to produce good quieting (more than 30 DB quieting). Adjust R 147 for reading of 3.8 to 4.0 volts at the collector of Q109.
- 2-5-2 Remove the "Reference" signal and have the unit squelched and receiving no signal. The voltage on the collector of Q109 shall be between 3.2 and 4.6 volts. If not, note voltage and proceed to Step 2-5-3. If voltage is between 3.2 and 4.6 volts, AFC alignment is complete.
- NOTE: Any further adjustment made to L128 and R147 will require AFC to be re-adjusted.

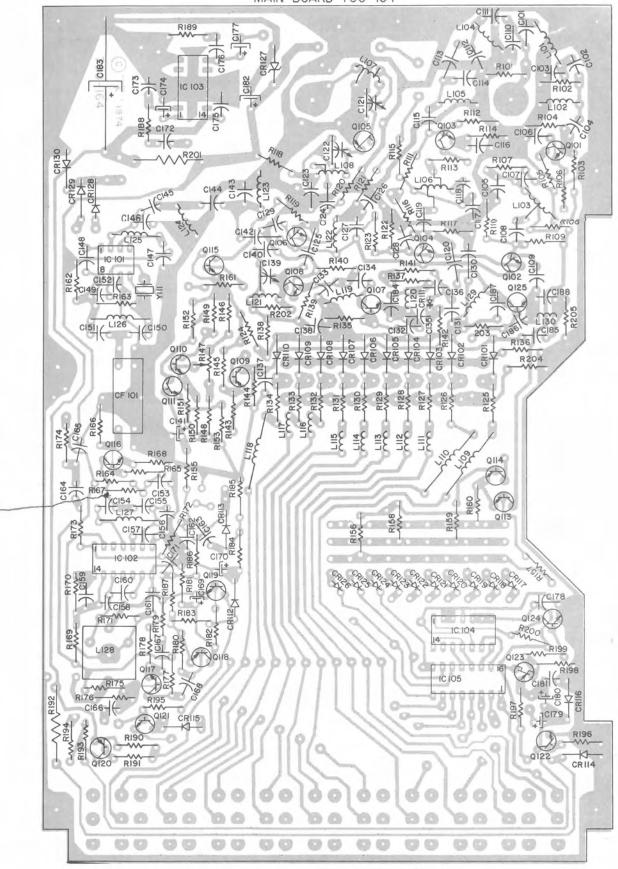
- 2-5-3 Inject "Reference" signal and monitor voltage on collector of Q109. Adjust L128 for same voltage as noted in Step 3. Readjust R147 for a voltmeter reading of 3.8 to 4.0 volts. Repeat Step 2-5-2.
- NOTE: Do not adjust L128 more than 1/4 turn at a time.
- 2-5-4 If an accurate I.F. signal source is not available, an approximate AFC alignment can be made by adjusting L128 on a High Band or Low Band crystal as specified in Quadrature Detector Alignment (Section 2-2), and with the unit squelched and receiving no signal, adjust R147 for voltmeter reading of 3.2 to 4.6 on the collector of Q109.
- NOTE: Units equipped with a 10.245 MHz crystal have the jumper in the AFC circuit connected between the base of Q109 and collector of Q111. When a 11.155 MHz crystal is used, the jumper is connected between the base of Q109 and the collector of Q110. If the crystal is changed from one frequency to the other, the jumper MUST be also changed. If the UHF, first L.O. crystals are made for high side injection (to eliminate a primary image problem in certain areas of the country), the jumper must be changed.

### SECTION 3 DIAGRAMS, VOLTAGE DATA AND SCHEMATIC

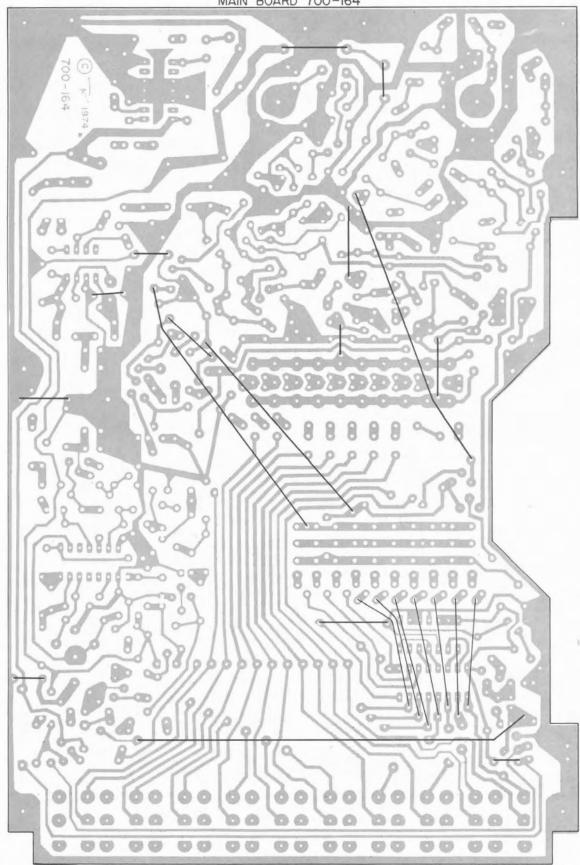
- 3-1 MAIN BOARD PARTS PLACEMENT DIAGRAM
- 3-2 MAIN BOARD BOTTOM VIEW
- 3-3 MAIN BOARD JUMPER PLACEMENT (BOTTOM VIEW) DIAGRAM
- 3-4 LIGHT BOARD PARTS PLACEMENT DIAGRAM
- 3-5 LIGHT BOARD BOTTOM VIEW
- **3-6 VOLTAGE DATA**
- 3-7 CRYSTAL LOCATION DIAGRAM
- 3-8 SCHEMATIC



3-1 MAIN BOARD PARTS PLACEMENT DIAGRAM

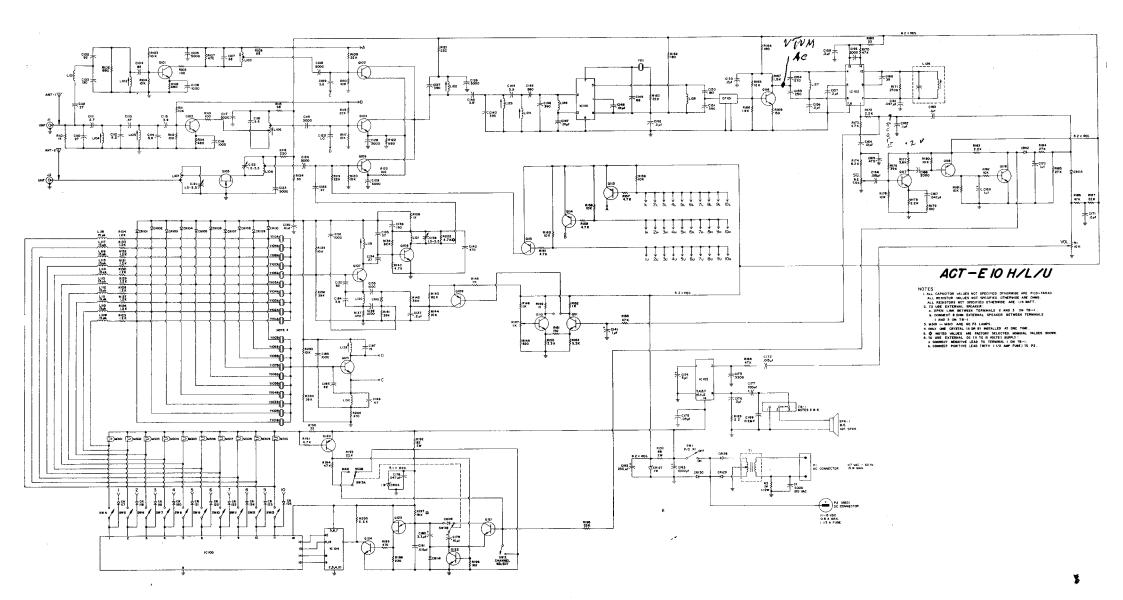


3-2 MAIN BOARD BOTTOM VIEW



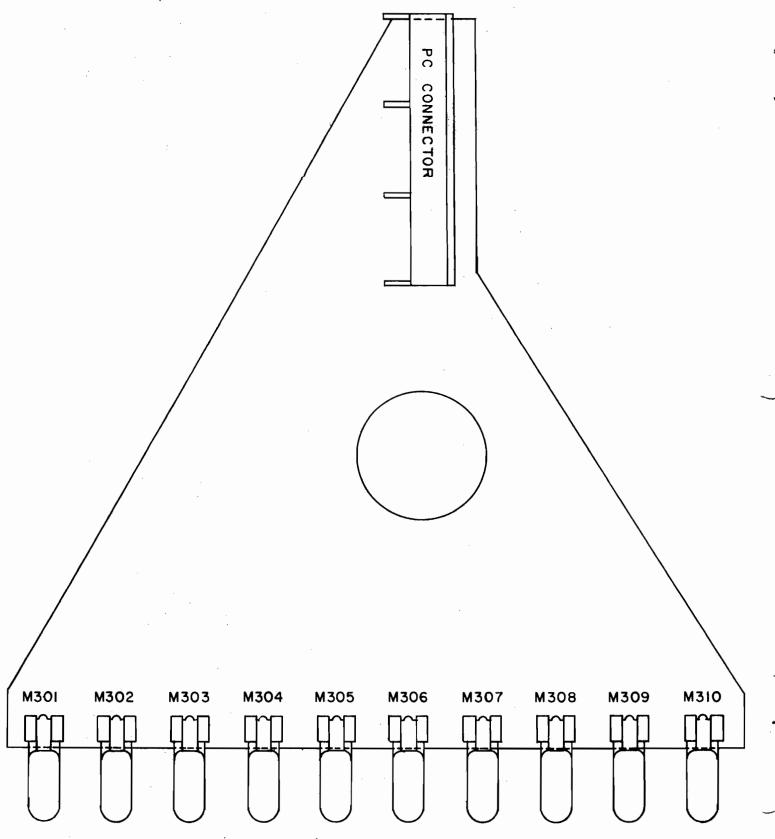
JUMPERS ARE LOCATED TOP SIDE. DIAGRAM SHOWS COPPER SIDE FOR PROPER CONNECTIONS.

3-3 MAIN BOARD JUMPER PLACEMENT (BOTTOM VIEW) DIAGRAM

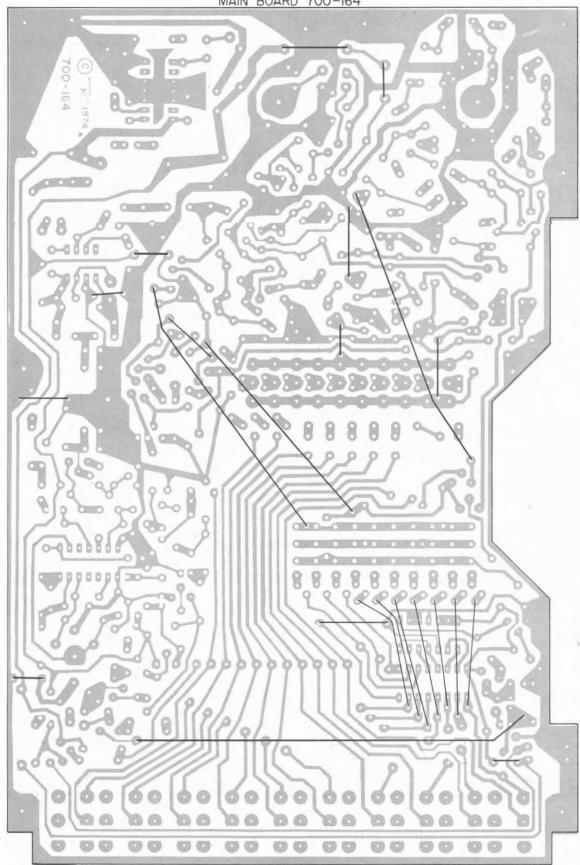


3-8 SCHEMATIC

LAMP BOARD 501-132



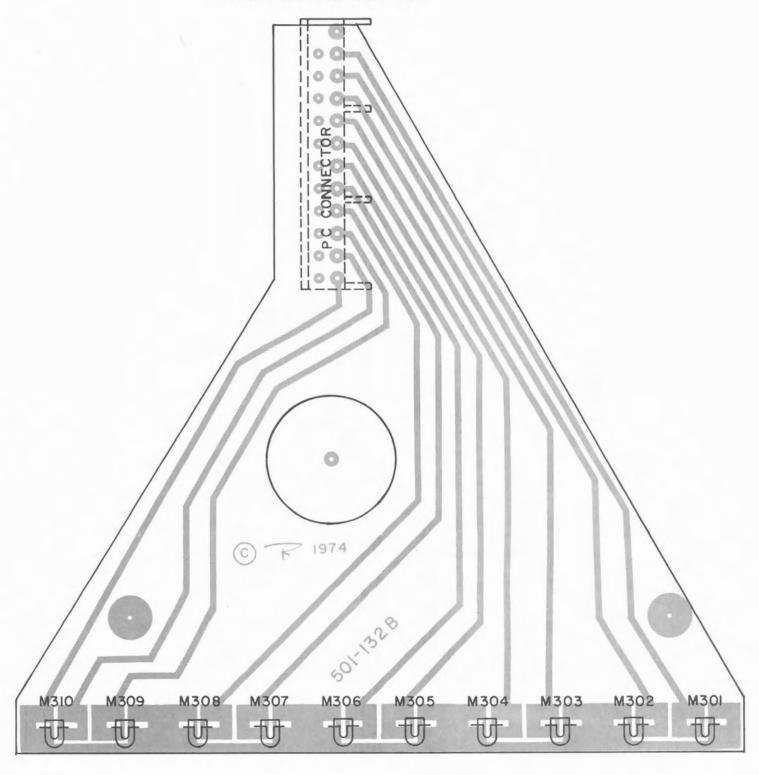
3-4 LIGHT BOARD PARTS PLACEMENT DIAGRAM



JUMPERS ARE LOCATED TOP SIDE. DIAGRAM SHOWS COPPER SIDE FOR PROPER CONNECTIONS.

3-3 MAIN BOARD JUMPER PLACEMENT (BOTTOM VIEW) DIAGRAM





3-5 LIGHT BOARD BOTTOM VIEW

### 3-6 VOLTAGE DATA

NOTE: All voltages are nominal and are measured with a VTVM. SCAN indicates the unit is scanning. MAN indicates the unit is not scanning and is stopped at channel 1. A "P" beside a voltage indicates that the meter reading is pulsating (fluctuating) because the scanner section of the unit is operating.

### **VOLTAGE DATA – SEMICONDUCTORS:**

	MITTER (Source)	BASE (Gate)	COLLECTOR (Drain)	
Q101	3.1 0 0	3.8 0 0	7.0 0 0	Low Band Activated High Band Activated UHF Band Activated
Q102	1.6 1.6 1.4	2.3 0 0	7.7 7.7 7.7	Low Band Activated High Band Activated UHF Band Activated
Q103	0 3.1 0	0 3.8 0	8.2 7.9 8.2	Low Band Activated High Band Activated UHF Band Activated
Q104	1.6 1.6 1.4	0 2.3 0	7.7 7.7 7.7	Low Band Activated High Band Activated UHF Band Activated
Q105 (FET)	0	0	6.0	
Q106	1.6 1.6 1.6	0 0 2.3	7.7 7.7 7.7	Low Band Activated High Band Activated UHF Band Activated
Q107	3.7 3.4	4.4 4.0	7.3 7.3	No Crystal With Crystal
Q108	0 0	.4 .1	7.3 4.0	UHF Band (No Crystal) UHF Band (With Crystal)
Q109 (PNP)	7.9	7.2	3-5	
Q110	2.9	3.6	7.2	
Q111	2.9	3.6	7.4	
Q113 (PNP)	8.2 8.2 8.2	7.5 8.2 8.2	8.1 0 0	Low Band Activated High Band Activated UHF Band Activated
Q114 (PNP)	8.2 8.2 8.2	8.2 7.5 8.2	0 8.1 0	Low Band Activated High Band Activated UHF Band Activated
Q115 (PNP)	8.2 8.2 8.2	8.2 8.2 7.5	0 0 8.1	Low Band Activated High Band Activated UHF Band Activated

### **VOLTAGE DATA (CONTINUED)**

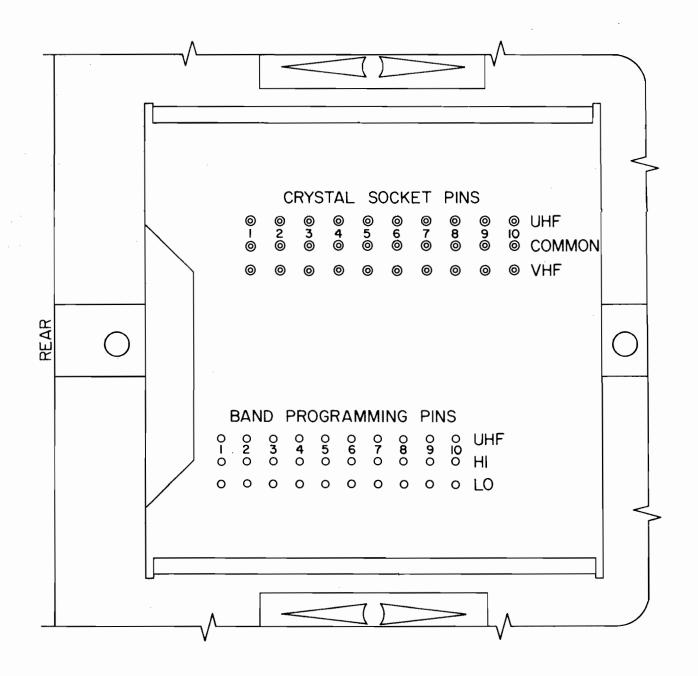
TRANSISTOR	EMITTER (Source)	BASE (Gate)	COLLECTOR (Drain)	
Q116	0.4	1.1	4.5	
Q117	1.0	1.7	5.0	
Q118	8.2 8.2 8.2	8.2 8.2 8.2	0 1.0 1.5	(Unsquelched) (Squelched) Min. (Tight Squelched)
Q119	0 0 0	0 0.8 0.8	7.2 0.2 0.1	(Unsquelched) (Squelched) (Tight Squelched)
Q120	13.8 13.8 13.8	13.1 13.1 13.8	13.6 13.6 0	(SCAN) (MAN) (No Lights)
Q121	0 0	0.8	4.0 0.1	(SCAN) (MAN)
Q122	0	0.8	0.1	
Q124	0 0	.2 .2	4.9 5.1	(SCAN) (MAN)
Q125	3.7 3.4	4.4 4.0	7.3 7.3	No Crystal With Crystal
	BASE 1	EMITTER	BASE 2	
Q123	0.2	3.8	5.1	(SCAN)
(Unijunction)	0.2	0.5	5.1	(MAN)
	CATHODE	ANODE		
CR113	1.8 1.0	2.4 0		(Unsquelched) (Squelched)

# **VOLTAGE DATA (CONTINUED)**

## INTEGRATED CIRCUITS

A "P" beside a voltage indicates that the meter reading is pulsating (fluctuating) because the scanner section of the unit is operating. MAN indicates the unit is not scanning and is at channel 1 (M301 is lighted). NOTE:

				Manual	SCAN	Manual	SCAN
16		١	1	ł	1	5.1	5.1
15	1		i	ì	1		2 <b>P</b>
14	I	2.0	13.8	Т.	2 <b>P</b>	-:	1P
13	ļ	9.7	0	0	0	1.	2P
12	I	3.5	0	Т.	11	Т.	1 <b>P</b>
1	1	2.9	0	Т.	2 <b>P</b>	11.2	9 <b>b</b>
10	i	1.4	0	0	0	11.2	9P
6	I	0.2	0	<del>-</del> :	2 <b>P</b>	11.2	9P
∞	7.8	0	6.9	Т.	IP	0	0
7	4.2	0	0	5.1	5.1	11.2	9 <b>P</b>
9	0	1.3	.01	5.1	5.1	11.2	9P
5	7.8	1.3	0	5.1	5.1	11.2	9P
4	4.2	1.3	0	0	0	11.2	9P
B	0.7	0	0	Q	0	11.2	9P
2	0.7	3.5	.01	0	0	11.2	9P
_	4.2	4.0	7.1	5.1	4.9	3.	9P
IC No.	IC101	IC102	IC103	IC104		IC105	



### 3-7 CRYSTAL LOCATION DIAGRAM

### **SECTION 4 PARTS LIST**

NOTE: When ordering parts, please include the following information:

- a. Model Number (ACT-E 10 H/L/U)
- b. Item Number
- c. Description
- d. Part Number

Item No	. Description	Part No.	Item N	o. Description	Part 👵 .
	RESISTORS		R156	10K, 10%, ¼W	4701-0103-0
R101	1K, 10%, ¼W	4701-0102-042	R157	4.7K, 10%, ¼W	4701-0472-0
R102	680 ohm, 10%, ¼W	4701-0681-042	R158	10K, 10%, ¼W	4701-0103-0
R103	10K, 10%, ¼W	4701-0103-042	R159	4.7K, 10%, ¼W	4701-0472-0
R104	10K, 10%, ¼W	4701-0103-042	R160	10K, 10%, ¼W	4701-0103-0
R105	100 ohm, 10%, ¼W	4701-0101-042	R161	4.7K, 10%, ¼W	4701-0472-0
R106	680 ohm, 10% ¼W	4701-0681-042	R162	180 ohm, 10%, ¼W	4701-0181-0
R107	470 ohm, 10%, ¼W	4701-0471-042	T163	22K, 10%, ¼W	4701-0223-0
R108	68 ohm, 10%, ¼W	4701-0680-042	R164	180 ohm, 10%, ¼W	4701- <b>0</b> 181-0
R109	22K, 10%, ¼W	4701-0223-042	R165	12K, 10%, ¼W	4701-0123-0
R110	10K, 10%, ¼W	4701-0103-042	R166	1.8K, 10%, ¼W	4701-0182-0
R111	10K, 10%, ¼W	4701-0103-042	R167	1.5K, 10%, ¼W	4701-0152-0
R112	10K, 10%, ¼W	4701-0103-042	R168	150 ahm, 10%, ¼W	4701-0151-0
7113	100 ohm, 10%, ¼W	4701-0101-042	R169	33 ohm, 10%, ¼W	4701-0330-0
3114	680 ohm, 10%, ¼W	4701-0681-042	- R170	47K, 10%, ¼W	4701-0473-0
R115	68 ohm, 10%, ¼W	4701-0680-042	R171	270K, 10%, ¼W	4701-0274-0
R116	22K, 10%, ¼W		R172	2.2K, 10%, ¼W	4701-0222-0
3117	10K, 10%, ¼W	4701-0223-042	R173	4.7K, 10%, ¼W	4701-0472-0
		4701-0103-042	R174	8.2K, 10%, ¼W	4701-0822-0
R118	220 ohm, 10%, ¼W	4701-0221-042	R175	39K, 10%, ¼W	4701-0322-0
R119	22K, 10%, ¼W	4701-0223-042	R176	10K, 10%, ¼W	4701-0103-0
R120	10K, 10%, ¼W	4701-0103-042	R177		4701-0103-0
7121	220 ohm, 10%, ¼W	4701-0221-042		5.6K, 10%, ¼W 2.2K, 10%, ¼W	
R122	680 ohm, 10%, ¼W	4701-0681-042	R178	, .	4701-0222-0
R123	100 ohm, 10%, ¼W	470 <b>1-</b> 0101-042	R179	100 ohm, 10%, ¼W	4701-0101-0
R124	33 ohm, 10%, ¼W	4701-0330-042	R180	10K, 10%, ¼W	4701-0103-0
R125	1.2K, 10%, ¼W	4701-0122-042	R181	10K, 10%, ¼W	4701-0103-0
3126	1.2K, 10%. ¼W	4701-0122-042	R182	10K, 10%, ¼W	4701-0103-0
3127	1.2K, 10%, ¼W	4701-0122-042	R183	2.2K, 10%, ¼W	4701-0222-0
3128	1.2K, 10%, ¼W	4701-0122-042	R184	27K, 10%, ¼W	4701-0273-0
3129	1.2K, 10%, ¼W	4701-0122-042	R185	27K, 10%, ¼W	4701-0273-0
R130	1.2K, 10%, ¼W	4701-0122-042	R186	47K, 10%, ¼W	4701-0473-0
R131	1.2K, 10%, ¼W	4701-0122-042	R187	22K, 10%, ¼W	4701-0223-0
1132	1.2K, 10%, ¼W	4701-0122-042	R188	47K, 10%, ¼W	4701-0473-0
R133	1.2K, 10%, ¼W	4701-0122-042	R189	2.2 ohm, 10%, ¼W	4701 <i>-</i> 0229-0
R134	1.2K, 10%, ¼W	4701-0122-042	R190	33 ohm, 10%, ¼W	4701-0330-0
₹135	10K, 10%, ¼W	4701-0103-042	R191	4.7K, 10%, ¼W	4701-0472-0
R136	39K, 10%, ¼W	4701-0393-042	R192	82 ohm, 5%, 2W	4710- 0820-
R137	470 ohm, 10%, ¼W	4701-0471-042	R193	22K, 10%, ¼W	4701-0223-0
₹138	1K, 10%, ¼W	4701-0102-042	R194	47K, 10%, ¼W	4701-0473-0
R139	82K, 10%, ¼W	4701-0823-042	R195	33K ,10%, ¼W	4701-0333-0
R140	4.7K, 10%, ¼W	4701-0472-042	R196	18K, 10%, ¼W	4701-0183-0
R141	39K, 10%, ¼W	4701-0393-042	R197	18K, 10%, ¼W	4701-0183-0
₹142	39K, 10%, ¼W	4701-0393-042	R198	220 ohm, 10%, ¼W	4701-0221-0
R143	82K, 10%, ¼W	4701-0823-042	R199	470 ohm, 10%, ¼W	4701-0471-0
R144	10K, 10%, ¼W	4701-0103-042	R200	2.2K, 10%, ¼W	4701-0222-0
1145	1K, 10%, ¼W	4701-0102-042	R201	68 ohm, 5%, 2W	4710-0680-0
146	1K, 10%, ¼W	4701-0102-042	R202	4.7K, 10%, ¼W	4701-0472-0
1147	1K, Trimmer (Vert.)	4751-0102-042	R203	10K, 10%, ¼W	4701-0103-0
1147	820 ohm, 10%, ¼W	4701-0821-042	R204	39K, 10%, ¼W	4701-0393-0
	1K, 10%, ¼W		R205	470 ohm, 10%, ¼W	4701-0393-0
1150	3.3K, 10%, ¼W	4701-0102-042			4,01-04/1-0
	· ·	4701-0332-042		CAPACITORS	
1151	150 ohm, 10%, ¼W	4701-0151-042	C101	27 pf, 10%, NPO, 50V (Disc.)	1500-0270-6
152	1K, 10%, ¼W	4701-0102-042	C102	82 pf, 5%, NPO, 50V (Disc.)	1524-0820-0
	3.3K, 10%, ¼W	4701-0332-042	C103	120 pf, 5%, 50V (Mica)	1506-0121-5
e i bb	47K, 10%, ¼W	4701-0473-042	C104	82 pf, 5%, NPO, 50V (Disc.)	1524-0820-0

Item No	. Description	Part No.	tem No.	. Description	Part No.
	CAPACITORS (Cont'd.)	C	163	.1 mfd, 20%, 12V (Disc.)	1502-0104-00
C105	.005 mfd, +80-20%, 500V (Disc.)	1503-0502-002 C	164	.01 mfd, 10%, 100V (Mylar Film)	1508-0103-61
2106	.001 mfd, +80-20%, 500V (Disc.)	1503-0102-001 C	165	470 pf, 20%, 50V (Disc.)	1523-0471-00
107	68 pf, 5%, NPO, 50V (Disc.)	1524-0680-002 C	166	.015 mfd, 10%, 100V (Mular Film)	1508-0153-61
108	.005 mfd, +80-20%, 500V (Disc.)	1503-0502-002 C	167	.047 mfd, 10%, 100V (Mylar Film)	1508-0473-61
C1 <b>09</b>	5.6 pf, 10%, NPO, 500V (Disc.)	1500-0569-905 C	168	.002 mfd, 20%, 50V (Disc.)	1523-0202-00
110	27 pf, 10%, NPO, 50V (Disc.)	1500-0270-650 C	169	1 mfd, 16V, 85°C (Electrolytic)	1513-0010-00
111	2.7 pf, +.25 pf, NPO, 500V (Disc.)	1500-0279-205 C	170	1 mfd, 16V, 85°C (Electrolytic)	1513-0010-00
0112	8.2 pf, 10%, NPO, 500V (Disc.)	1	171	.2 mfd, +80-20%, 12V (Disc.)	1502-0204-00
2113	.47 pf, 10%, (Composition)		172	.015 mfd, 10%, 100V (Mylar Film)	1508-0153-61
2114	5.6 pf, 10%, NPO, 500V (Disc.)	•	2173	.0033 mfd, 10%, 100V (Mylar Film)	1508-0332-61
2115	3.0 pf, 10%, NPO, 500V (Disc.)		0174	5 mfd, 10V, 85°C (Electrolytic)	1513-0050-00
2116	.001 mfd, +80-20%, 500V (Disc.)		2175	.05 mfd, +80-20%, 25V (Disc.)	1502-0503-00
2117	.005 mfd, +80-20%, 500V (Disc.)		2176	.2 mfd, +80-20%, 12V (Disc.)	1502-0303-00
2118	5.6 pf, 10%, NPO, 500V (Disc.)		2170	100 mfd, 16V, 85°C (Electrolytic)	1513-0101-00
2119	.005 mfd, +80-20%, 500V (Disc.)		2178		
2120	1 pf, 10%, (Composition)			.047 mfd, 10%, 100V (Mylar Film)	1508-0473-61
121			C1 79	10 mfd, 10V, 85°C (Electrolytic)	1513-0100-00
	1.5-5.5 pf, Trimmer		2180	3.3 mfd, 20%, 10V, 85°C (Elect.)	1513-0339-00
2122	1.5-5.5 pf, Trimmer		181	.015 mfd, 10%, 100V (Mylar Film)	1508-0153-61
123	.005 mfd, +80-20%, 500V (Disc.)		182	250 mfd, 10V, 85°C (Electrolytic)	1513-0251-00
C124	.005 mfd, +80-20%, 500V (Disc.)		183	1000 mfd, 16V 85°C (Electrolytic)	1513-0102-00
125	,47 pf, 10%, (Composition)		2184	3.9 pf, 10%, NPO, 500V (Disc.)	1500-0399-90
126	.005 mfd, +80-20%, 500V (Disc.)		185	.001 mfd, +80-20%, 500V (Disc.)	1503-0102-00
2127	390 pf, 5%, 50V (Mica)		2186	82 pf, 5%, NPO, 50V (Disc.)	1524-0820-00
128	.005 mfd, +80-20%, 500V (Disc.)		C187	15 pf, 10%, NPO, 50V (Disc.)	1500-0150-69
129	.005 mfd, +80-20%, 500V (Disc.)		188	47pf, 5%, NPO, 50V (Disc.)	1524-0470-0
130	.01 mfd, +80-20%, 500V (Disc.)		C189	0.2 mf·d, +80 -20%, 12V (Disc.)	1502-0204-0
131	.001 mfd, +80-20%, 500V (Disc.)	1503-0102-001	404	COILS	4000 0000 0
2132	82 pf, 5%, NPO, 50V (Disc.)		_101	Choke, .68 uhy	1802-0688-0
2133	27 pf, 10%, NPO, 50V (Disc.)	1000 02/0 000	_102	Input, RF AMP (Green)	1800-3152-00
134	27 pf, 10%, NPO, 50V (Disc.)	1000 0270 000	_103	Output, RF AMP (Yellow)	1800-3152-0
135	.001 mfd, +80-20%, 500V (Disc.)	.000 0.02 00.	_104	Input, RF AMP (Red)	1800-3152-00
2136	.001 mfd, +80-20%, 500V (Disc.)	1000 0 102 00 1	_105	Input, RF AMP (Red)	1800-3152-0
137	.2 mfd, +80-20%, 12V (Disc.)	. OOL OLO . OOO	_106	Output, RF AMP (Orange)	1800-3152-00
138	150 pf, 20%, 50V (Disc.)	1523-0151-002 L	_107	Input, RF AMP (UHF)	1800-3160-00
139	1.5-5.5 pf, Trimmer	1517-0000-011	_108	Output, RF AMP (UHF)	1800-3160-00
140	470 pf, 20%, 50V (Disc.)	1523-0471-002 L	_109	Choke, 15 uhy	1802-0152-00
141	1 mfd, 16V, 85°C (Electrolytic)	1513-0010-002	_110	Choke, 15 uhy	1802-0152-00
142	3.9 pf, 10% (Composition)	1510-0399-900 L	_111	Choke, 15 uhy	1802-0152-00
143	390 pf, 5%, 50V (Mica)		_112	Choke, 15 uhy	1802-0152-00
144	3.9 pf, 10%, NPO, 500V (Disc.)		_113	Choke, 15 uhy	1802-0152-0
145	680 pf, 5%, 50V (Mica)		_114	Choke, 15 uhy	1802-0152-00
146	390 pf, 5%, 50V (Mica)		_115	Choke, 15 uhy	1802-0152-0
147	.005 mfd, +80-20%, 500V (Disc.)		_116	Choke, 15 uhy	1802-0152-0
148	.01 mfd, +80-20%, 25V (Disc.)	.000 0002 002	_117	Choke, 15 uhy	1802-0152-0
149	68 pf, 5%, NPO, 50V (Disc.)		_118	Choke, 15 uhy	1802-0152-0
150	180 pf, 5%, 50V (Mica)	.02.000000	_119	Oscillator, Collector (White)	1800-3152-0
	390 pf, 5%, 50V (Mica)		_120	Oscillator, Emitter	1801-1236-9
151			_121	Tripler, Collector	1800-3160-0
152	.2 mfd, +80-20%, 12V (Disc.)		_121	10.7 MHz IF (White)	1800-3191-4
153	.2 mfd, +80-20%, 12V (Disc.)				
154	270 pf, 5%, 50V (Mica)		_123 	10.7 MHz IF (White)	1800-3191-4
155	250 pf, 5%, 50V (Mica)		_124	10.7 MHz IF (Yellow)	1800-3191-4
156	.2 mfd, +80-20%, 12V (Disc.)		_125	Choke, 6.8 uhy, 10%	1802-0689-0
157	.2 mfd, +80-20%, 12V (Disc.)		_126	Choke, 820 uhy	1802-0000-0
158	.2 mfd, +80-20%, 12V (Disc.)	.0-2 020 . 000	_127	Choke, 820 uhy	1802-0000-0
159	.002 mfd, 20%, 50V (Disc.)		_128	Quadrature Detector	1800-3151-7
160	39 pf, 10%, NPO, 50V (Disc.)	1500-0390-650 L	_129	Oscillator, Collector (White)	1800-3152-0
161	.047 mfd, 10%, 100V (Mylar Film)	1508-0473-610			
162	.1 mfd, 20%, 12V (Disc.)	1502-0104-005			

Item No.	Description	Part No.	Item No	o. Description	Part No.
	DIODES		Q1 25	Silicon NPN	4801-0000-100
CR101	Germanium-junction, signal	4807-1233-900		INTEGRATED CIRC	JITS
	Germanium—junction, signal	4807-1233-900	IC101	IF Amplifier	3130-3167-90
	Germanium-junction, signal	4807-1233-900	IC102	Limiter/Quadrature detector	3130-3157-603
	Germanium—junction, signal	4807-1233-900	IC103	Audio amplifier	3130-3157-614
	Germanium-junction, signal	4807-1233-900	IC104	Counter	3130-3157-608
	Germanium—junction, signal	4807-1233-900	1C105	Decoder/Driver	3130-3193-50
	Germanium—junction, signal	4807-1233-900		2000401, 20000	
	Germanium—junction, signal	4807-1233-900		CRYSTAL	
	Germanium—junction, signal	4807-1233-900	Y111	10.245 MHz (Standard)	2301-3151-60
	Germanium—junction, signal	4807-1233-900	Y111	11.155 MHz (Special)	2301-3151-60
	Varactor, SMV 1172	4809-0000-001			
	Silicon, signal	4805-1241-200		FILTER	
	Silicon, signal		CF101	Ceramic, 455 KHz	2700-0000-00
		4805-1241-200		MACOULL ANDOUG	
	Zener, 5.1 V, 5%, 1W	4808-0000-007		MISCELLANEOUS	
	Silicon, signal	4805-1241-200		Socket Pin, Crystal Mounting	2830-3216-40
	Silicon, signal	4805-1241-200		Terminal, Female (PC Mount)	2106-0000-00
	Silicon, signal	4805-1241-200		Terminal, Male (PC Mount)	2107-0000-00
	Silicon, signal	4805-1241-200		Terminal, Female (Wire Mount)	2107-0000-00
	Silicon, signal	4805-1241-200		Connector, 11-pin, PC Mount	2105-0000-01
	Silicon, signal	4805-1241-200		Shield (Straight section)	2508-1256-30
	Silicon, signal	4805-1241-200		Shield (L-shaped section)	2508-1256-40
	Silicon, signal	4805-1241-200			
	Silicon, signal	4805-1241-200			
	Silicon, signal	4805-1241-200			
	Silicon, signal	4805-1241-200			
	Silicon, signal	4805-1241-200			
	Zener, 8.2V, 5%, 1W	4808-0000-009			
	Silicon, rectifier	4806-0000-004			
	Silicon, rectifier	4806-0000-004			
CR130	Silicon, rectifier	4806-0000-004			
	TRANSISTORS				
	Silicon, NPN (Red top)	4801-0000-035		•	
	Silicon, NPN (Red top)	4801-0000-035			
	Silicon, NPN (Red top)	4801-0000-035			
	Silicon, NPN (Red top)	4801-0000-035			
	Field effect, junction	4811-0000-015			
	Silicon, NPN (Red top)	4801-0000-035			
	Silicon, NPN	4801-0000-100			
	Silicon, NPN (Red top)	4801-0000-035			
	Silicon, PNP (White top)	4801-0000-060			
Q110 :	Silicon, NPN	4801-0000-010			
Q111 :	Silicon, NPN	4801-0000-010			
	Silicon, PNP (White top)	4801-0000-060			
Q114	Silicon, PNP (White top)	4801-0000-060			
Q115	Silicon, PNP (White top)	4801-0000-060			
	Silicon, NPN	4801-0000-010			
Q117	Silicon, NPN	4801-0000-010			
Q118 :	Silicon, PNP (White top)	4801-0000-060			
Q119 :	Silicon, NPN	4801-0000-010			
Q120	Silicon, PNP (White top)	4801-0000-060			
Q1 21	Silicon, NPN	4801-0000-010			
	Silicon, NPN	4801-0000-010			
Q123	Silicon, PN, unijunction	4813-0000-001			
	Silicon, NPN	4801-0000-010			

Item No	. Description	Part No.	Item No.	Description	Part No.
	LAMPS				
M301	Incaridescent, 14.4V, 80 MA.	3901-0000-007	Label,	Crystal Access Door .	2507-5117-800
M302	Incandescent, 14.4V, 80 MA.	3901-0000-007	Latch,	rotary (access door)	2402-1293-800
M303	Incandescent, 14.4V, 80 MA.	3901-0000-007		g, antenna (UHF)	2501-0000-006
M304	Incandescent, 14.4V, 80 MA.	3901-0000-007	Bushin	g, antenna (VHF)	2501-0000-007
M305	Incandescent, 14.4V, 80 MA.	3901-0000-007	Foot, F		1401-0000-001
M306	Incandescent, 14.4V, 80 MA.	3901-0000-007	Label	frequency/service	2507-1278-100
M <b>3</b> 07	Incandescent, 14.4V, 80 MA.	3901-0000-007	-	, Owner's Instruction	7001-1059-600
				, Service (\$5.00 prepaid)	SM-10-596
M308	Incandescent, 14.4V, 80 MA.	3901-0000-007	Walldal	, service (40.00 prepaid)	3141-10-330
M30 <del>9</del> M310	Incandescent, 14.4V, 80 MA. Incandescent, 14.4V, 80 MA.	3901-0000-007 3901-0000-007			
	MISCELLANEOUS				
	Clip, Lamp Mounting	2830-5106-600			
	(2 required per lamp)				
	Connector, 12-pin, PC Mount	2105-0000-016			
	Connector (10-pin) and wire				
	assembly	7011-1069-000			
4-3 CH	ASSIS ASSEMBLY				
	ELECTRICAL COMPON	ENTS			
R1	10K, Volume control/SW-1	4750-3212-101			
R2	7.5K, Squelch control	4750-3212-102			
R3	1 Meg, 10%, 1/2W	4701-0105-044			
C1	.005 Mfd, +80-20%, 1400 V (Disc.)	1500-0502-002			
J1	Connector, Antenna	2105-0000-005			
J2	Connector, Antenna	2105-0000-005			
P1	Connector, AC	2105-1279-100			
P2	Connector, DC (Red)	2105-1277-900			
ת	Transformer, Power	5604-5100-600			
Y100	Crystal, Receive, 30-50 MHz	2303-0000-000			
Y100	Crystal, Receive, 148-174 MHz	2302-0000-000			
Y100	Crystal, Receive, 450-470 MHz	2304-0000-000			
Y100	Crystal, Receive, 470-500 MHz	2320-0000-000			
1100	(Specify frequency on all crystals				
ANT-1	Antenna, Telescopic, H1/LO VHF	1201-5108-802			
		1201-5108-803			
	Antenna, Telescopic, UHF	1301-3236-000			
	Speaker, 8 ohm, 3½-inch, square				
	Switch, 2-station, push button Switch, 10-station, push button	5112-6035-820 5112-6038-401			
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	Terminal Board, 3-lug (rear panel)	2103-3007-907			
	Terminal strip, 3-lug	2103-3008-006			
	Power Cord, AC (MA-16) Power Cord, DC (MA-17)	6041-3215-900 7011-1047-800			
	MECHANICAL COMPON				
		2508-3236-200			
	Shield, AC connector				
	Speednut, speaker mounting	2853-0000-007			
	Screw, #6-32, Black	2804-0312-010			
	Mask, subpanel (speaker)	2514-3237-900			
	Panel, front	1405-6040-300			
	Lens, 10-station	3900-5100-801			
	Shield, light (tubular)	2508-1286-601			
	Knob, volume and squelch	2402-1276-202			
	Cabinet (wrap) assembly	1408-7017 <del>-4</del> 00			
	Panel, rear	1405-3167-503			
	Door, crystal access	1413-1293-900			

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